

### R8A66161DD/SP 16-BIT LED DRIVER WITH SHIFT REGISTER AND LATCH

REJ03F0262-0100 Rev. 1.00 Jan. 16. 2008

### DESCRIPTION

R8A66161 is a LED array driver having a 16-bit serial input and parallel output shift register function with direct coupled reset input and output latch function.

This product guarantees the output current of 24mA (Vcc =5V case) which is sufficient for anode common LED drive, capable of following 16-bits continuously at the same time. Parallel output is open drain output. In addition, as this product has been designed in complete CMOS, power consumption can be greatly reduced when compared with conventional BIPOLAR or Bi-CMOS products. Furthermore, pin layout ensures the realization of an easy printed circuit. R8A66161 is the succession product of M66311.

### **FEATURES**

- Anode common LED drive
- Vcc 5V or 3.3V single power supply
- High output current: all parallel outputs  $\overline{QA} \sim \overline{QP}$  IOL=24mA (at VCC =5.0V) IOL=12mA (at VCC =3.3V) simultaneous lighting available
- Low power dissipation: 100uW/package (max) (Vcc=5.0V, Ta=25 , quiescent state)
- High noise margin: Schmitt input circuit provides responsiveness to a long line length
- Equipped with direct-coupled reset
- Open drain output: (except serial data output SQP)
- Wide operating temperature range: Ta=-40°C~+85°C
- Pin layout facilitates printed circuit wiring. (This layout facilitates cascade connection and LED connection)

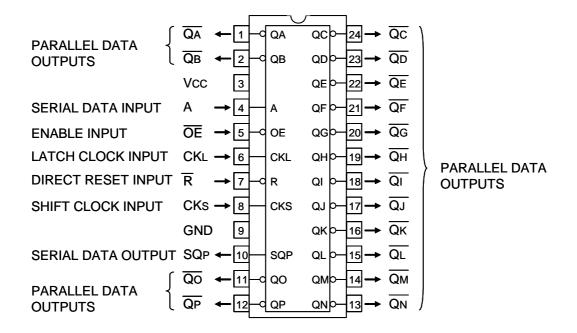
### **APPLICATION**

- LED array drive, The various LED display modules
- PPC, Printer, VCR, Mini-compo, Button-Telephone etc. All of LED display equipment

#### **BLOCK DIAGRAM** LOGIC DIAGRAM SERIAL PARALLEL DATA OUTPUTS DATA OUTPUT Qi $\overline{Q}M$ SQP Vcc (18 13 (20) (19 (10) (3) **PARALLEL SERIAL** DATA DATA **CKs** $\overline{\mathsf{R}}$ CKL GND **OE** Α **OUTPUTS** OUTPUT DATA signal SHIFT DIRECTLATCH ENABLE SERIAL SOP OE signal CLOCK RESET CLOCK INPUT DATA INPUT INPUT INPUT INPUT

OUTPUT FORMAT

### PIN CONFIGURATION (TOP VIEW)



#### **FUNCTIONAL DESCRIPTION**

As R8A66161 uses silicon gate CMOS process. It realizes high-speed and high-output currents sufficient for LED drive while maintaining low power consumption and allowance for high noises.

Each bit of a shift register consists of two flip-flop having independent clocks for shifting and latching.

As for clock input, shift clock input CKs and latch clock input CKL are independent from each other, shift and latch operations being made when "L" changes to "H".

Serial data input A is the data input of the first-step shift register and the signal of A shifts shifting registers one by one when a pulse is impressed to CKs. When A is "H", the signal of "L" shifts.

When the pulse is impressed to CKL, the contents of the shifting register at that time are stored in a latching register, and they appear in the parallel data outputs from  $\overline{QA} \sim \overline{\overline{QP}}$ .

Outputs  $\overline{QA} \sim \overline{QP}$  are open drain outputs.

To extend the number of bits, use the serial data output SQP which shows the output of the shifting register of the 16th bit.

When reset input  $\overline{R}$  is changed to "L",  $\overline{QA} \sim \overline{QP}$  and SQP are reset. In this case, shifting and latching register are set.

If "H" is impressed to output enable input  $\overline{OE}$ ,  $\overline{QA} \sim \overline{QP}$  reaches the high impedance state, but SQP does not reach the high impedance state. Furthermore, change in  $\overline{OE}$  does not affect shift operation.

## FUNCTION TABLE (Note: 1)

0				Input									Paral	lel da	ıta ou	tput							Serial data	Remarks
Operation	on mode	R	CKs	CK∟	Α	<u>G</u>	Ιđ	Qв	Qc	Ιœ	۱ä	QF	QG	QH	Ιō	lđ	ĺακ	Ιď	Qм	Ιã	ΙĜ	ΙĜ	output SQP	Remarks
Re	set	۲	Х	Х	Х	Х	Z	Z	Z	Z	Z	Z	Ζ	Z	Z	Z	Z	Ζ	Z	Z	Z	Z	L	_
	Shift t1	Ι		Х	Η	L	βá	$Q_{B}^{O}$	$\frac{1}{2}$	မြိ	ĵä	မြီ	QG	QH	ĺα	မြိ	ĺά	ပြီ	QM	ŝ	ြိတိ	ြိုင်	qσ	Output
Shift	Latch t2	Ξ	Х		Х	٦	L	q <sub>A</sub> 0	q <sub>B</sub> 0	dc <sub>0</sub>	d⊳0	dE <sub>0</sub>	qF <sup>0</sup>	d <sub>G</sub> 0	qн	o اp	dηo	qĸ0	qL0	ф	dν <sub>0</sub>	qσ	do₀	Lighting " H "
Latch operation	Shift t1	Н		Х	L	L	QÃ	<mark>©</mark>	Qc	<u>~</u> °	QE	ğ	<u>S</u>	QH QH	ĺα̈́	<u>Q</u>	Qĸ	Qι°	QM	ဖြ	Qo	Qp <sup>0</sup>	qσ0	Output
	Latch t2	Ι	Х		Х	L	Ζ	q <sub>A</sub> 0	qв <sup>0</sup>	qc0	q₽	qE0	qF <sup>0</sup>	qG <sup>0</sup>	qн <sup>0</sup>	qı 0	ďο	qĸ <sup>0</sup>	qL0	qмρ	dν <sub>0</sub>	qσº	qo0	Lights-out " L "
Output	disable	Х	Х	Х	Χ	Н	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Z	Ζ	Z	qР	

: Change from low-level to high-level  $\overline{\mathbb{Q}}^0$  : Output state  $\overline{\mathbb{Q}}$  before CKL changed Note1:

: Irrelevant Х

 $\mathsf{q}^0$ : Contents of shift register before CKs changed

: Contents of shift register : t2 is set after t1 is set : High impedance

### ABSOLUTE MAXIMUM RATINGS (Ta=-40~+85 , unless otherwise noted)

Symbol	Paran	neter	Conditions	Ratings	Unit
VCC	Supply voltage			-0.5 ~ +7.0	V
VI	Input voltage			-0.5 ~ VCC+0.5	V
Vo	Output voltage			-0.5 ~ VCC+0.5	V
Ю	Output current per	QA ∼ QP		50	mA
10	output pin	SQP		±25	IIIA
ICC	Supply / GND current		VCC, GND	-20, +410	mA
Pd	Power dissipation		(Note 2)	500	mW
Tstg	Storage temperature range			-65 ~+150	

Note 2: R8A66161SP; Ta=-40  $\sim$  +70 , Ta=+70  $\sim$  +85 are derated at -6mW/ .

# RECOMMENDED OPERATING CONDITIONS (Ta=-40~+85 , unless otherwise noted)

Symbol	Parameter		Unit			
Symbol	Farameter	Min.	Тур.	Max.	Offic	
VCC	Cupply voltage	5.0V support	4.5	5.0	5.5	V
VCC	Supply voltage	3.0	3.3	3.6	V	
VI	Input voltage		0		VCC	V
Vo	Output voltage		0		VCC	V
Topr	Operating temperature range		-40		+85	

### **ELECTRICAL CHARACTERISTICS**

# ■5.0V version support specifications (Ta=-40~+85°C,Vcc=4.5V~5.5V, unless otherwise noted)

Symbol	Paramete		Toot on	nditions		Unit			
Symbol	Faramete	ı	lest co	mannons	Min.	Тур.	Max.	Offic	
VT+	Positive-going threshold voltage		VO=0.1V, VCC-  IO =20uA	-0.1V	0.35xVCC		0.70xVCC	V	
VT-	Negative-going thres voltage	hold	VO=0.1V, VCC-0.1V		0.20xVCC		0.55xVCC	٧	
			VI=VT+,VT-	IOL= 20uA			0.10		
VOL	Low-level output voltage	QA ∼ QP	VCC=4.5V	IOL= 24mA			0.53	V	
			(Note3)	IOL= 40mA			0.94		
Voн	High-level output	SQP	VI=VT+,VT-	IOH= -20uA	VCC-0.1			V	
VOH	voltage	SQP	VCC=4.5V	IOH= -4mA	3.66				
VOL	Low-level output	SQP	VI=VT+,VT-	IOL= 20uA			0.10	V	
VOL	voltage	SQP	VCC=4.5V	IOL= 4mA			0.53	V	
IIH	High-level input curre	ent	VI=VCC, VCC=	VI=VCC, VCC=5.5V			5	uA	
IIL	Low-level input curre	nt	VI=GND, VCC=	=5.5V			-5	uA	
IO	Maximum output	<del>-</del> -	VI=VT+,VT-	VO=VCC			10	uA	
Ю	leakage current	QA ∼ QP	VCC=5.5V	VO=GND			-10	uA	
ICC	Quiescent supply cur	rent	VI=VCC,GND, VCC=5.5V				200	uA	

Note 3: R8A66161 is used under the condition of an output current IOL=40mA, the number of simultaneous drive outputs is restricted as shown in the Duty Cycle – IOL of TYPICAL CHARACTERISTICS.

# ■3.3V version support specifications (Ta=-40~+85°C,Vcc=3.0V~3.6V, unless otherwise noted)

Symbol	Paramete	r	Tost or	onditions		Unit			
Symbol	Faramete	1	lest co	mailions	Min.	Тур.	Max.	Oill	
VT+	Positive-going threshold voltage		VO=0.1V, VCC-0.1V  IO =20uA		0.35xVCC		0.70xVCC	٧	
VT-	Negative-going thres voltage	hold	VO=0.1V, VCC-0.1V  IO =20uA		0.20xVCC		0.55xVCC	٧	
		<u> </u>	VI=VT+,VT-	IOL= 20uA			0.10		
VvOL	Low-level output voltage	QA ∼ QP	VCC=3.0V	IOL= 12mA			0.54	V	
	Voltage			IOL= 20mA			0.72		
Voн	High-level output	SQP	VI=VT+,VT-	,				V	
VOH	voltage	SQP	VCC=3.0V	IOH= -2mA	2.60			V	
VOL	Low-level output	SQP	VI=VT+,VT-	IOL= 20uA			0.10	V	
VOL	voltage	SQP	VCC=3.0V	IOL= 2mA			0.40	V	
liH	High-level input curre	ent	VI=VCC, VCC=	=3.6V			5	uA	
IIL	Low-level input curre	nt	VI=GND, VCC	=3.6V			-5	uA	
10	Maximum output		VI=VT+,VT-	VO=VCC			10		
Ю	leakage current	QA ∼ QP	VCC=3.6V	Vo=GND			-10	uA	
ICC	Quiescent supply cur	rent	VI=VCC,GND, VCC=3.6V				200	uA	

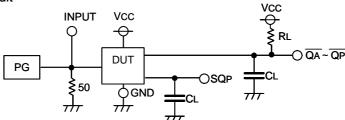
# SWITCHING CHARACTERISTICS (Ta=-40~+85°C,Vcc=5.0V or 3.3V)

Symbol	Paramet	Test	5.0V	specific	ation	3.3V	Unit			
Symbol	1 didificter		conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Offic
fmax	Maximum clock frequency					4			3.3	MHz
tPLH	Output "L"-"H" and "H"-"L"	CKs - SQP				125			150	ns
tPHL	propagation time	CNS - SQP				125			150	ns
tPHL	Output "H"-"L" propagation time	R – SQP				125			150	ns
tPLZ	Output "L"-"Z" propagation time	R - QA ~ QP (turned off)	CL=50pF			200			220	ns
tPZL	Output "Z"-"L" propagation time	CKL - QA ~ QP (turned on)	RL=1KΩ (Note 4)			125			150	ns
tPLZ	Output "L"-"Z" propagation time	CKL - QA ~ QP (turned off)				200			220	ns
tPZL	Output "Z"-"L" propagation time	OE - QA ~ QP (turned on)				125			150	ns
tPLZ	Output "L"-"Z" propagation time	OE - QA ~ QP (turned off)				200			220	ns
CI	Input capacitance					10			10	pF

# TIMING REQUIREMENTS (Ta=-40~+85°C,Vcc=5.0V or 3.3V)

Symbol	Parameter	Test	5.0V	specific	ation	3.3V	Unit		
Symbol	Farameter	conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Offic
tw	CKS, CKL, R pulse width		125			150			ns
tsu	A setup time with respect to CKS		125			150			ns
tsu	CKS setup time with respect to CKL	(Note 4)	125			150			ns
th	A hold time with respect to CKS		15			20			ns
trec	R recovery time with respect to CKS, CKL		70			80			ns

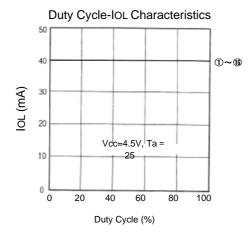
Note 4: Test Circuit

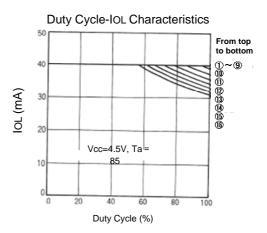


- (1) The pulse generator (PG) has the following characteristics (10%~90%). :tr = 6ns, tf = 6ns.
- (2) The capacitance CL includes stray wiring capacitance and the probe input capacitance.

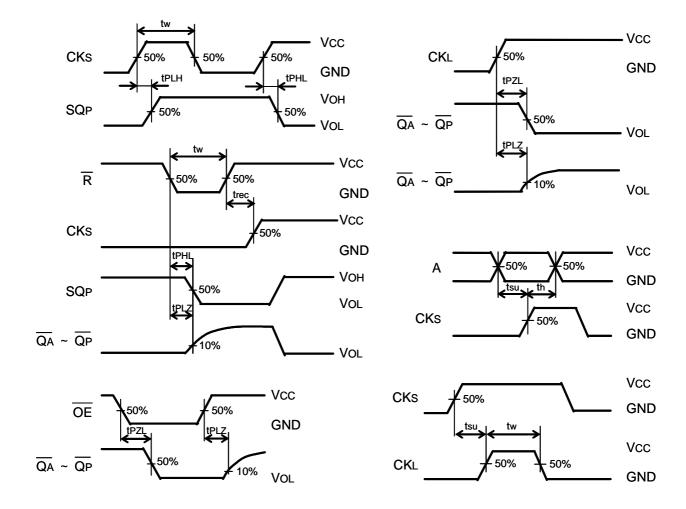
### TYPICAL CHARACTERISTICS

- Repetition frequency > 10 Hz
- \* Numbers in  $\bigcirc$  indicate the number of output circuits that operate simultaneously.
- \*Current values are per circuit.



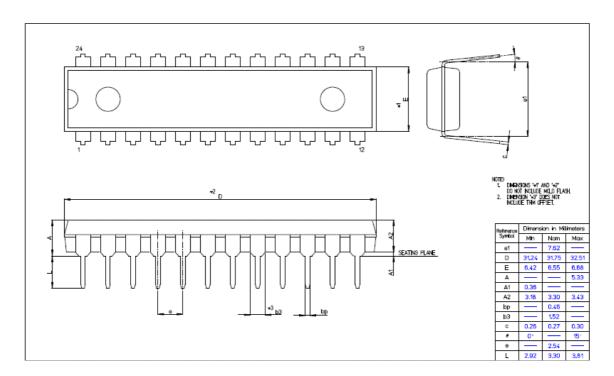


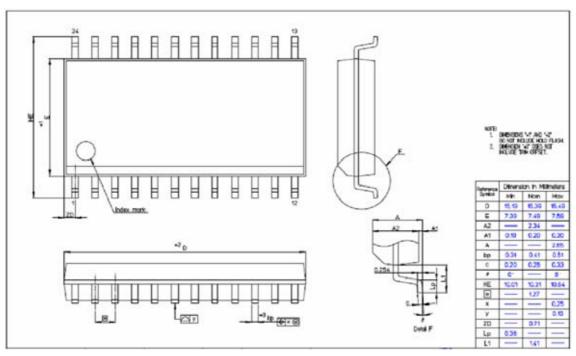
### **TIMING DIAGRAM**



# PACKAGE OUTLINE

Product name	Package	RENESAS Code	Previous Code
R8A66161DD	24pin DIP	PRDP0024AF-A	24P4X-A
R8A66161SP	24pin SOP	PRSP0024DF-A	24P2X-B





All trademarks and registered trademarks are the property of their respective owners.

### Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- tes:
  This document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas products for their use. Renesas neither makes warranties or representations with respect to the accuracy or completeness of the information contained in this document nor grants any license to any intellectual property rights or any other rights of Renesas or any third party with respect to the information in this document.

  Renesas shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, charts, programs, algorithms, and application circuit examples.

  You should not use the products or the technology described in this document for the purpose of military applications such as the development of weapons of mass destruction or for the purpose of any other military use. When exporting the products or technology described herein, you should follow the applicable export control laws and regulations, and procedures required by such laws and regulations.

- Tou should not use the products or the technology described in this document for the purpose of military applications such as the development of weapons of mass destruction or for the purpose of any other military use. When exporting the products of technology described herein, you should follow the applicable export control laws and regulations, and procedures required by such laws and regulations.
   All information included in this document such as product data, diagrams, charts, programs, algorithms, and application circuit examples, is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas products listed in this document, please confirm the latest product information included in this document, but Renesas assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document, but Renesas assumes no liability whatsoever for any damages incurred as a result of errors or omissions in the information included in this document, but Renesas assumes in light of the total system before deciding about the applicability of such information to the infended application. Renesas makes no representations, warranties or guaranties regarding the suitability of its products for any particular application and specifically disclaims any liability arising out of the application and use of the information in this document or Renesas products.
   With the exception of products specified by Renesas as suitable for automobile applications, Renesas products are not designed, manufactured or tested for applications or otherwise in systems the failure or malfunction of which may cause a direct threat to human life or create a risk of human injury or which require especially high quality and reliability such as astely systems, or equipment or systems for transportation and traffic, heldere, combustion control, aerospace and aeronau



http://www.renesas.com

#### RENESAS SALES OFFICES

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

**Renesas Technology Taiwan Co., Ltd.** 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510